

LARGE SCALE ELECTRONIC STRUCTURE COMPUTATIONS FOR PLASMA DEVICES

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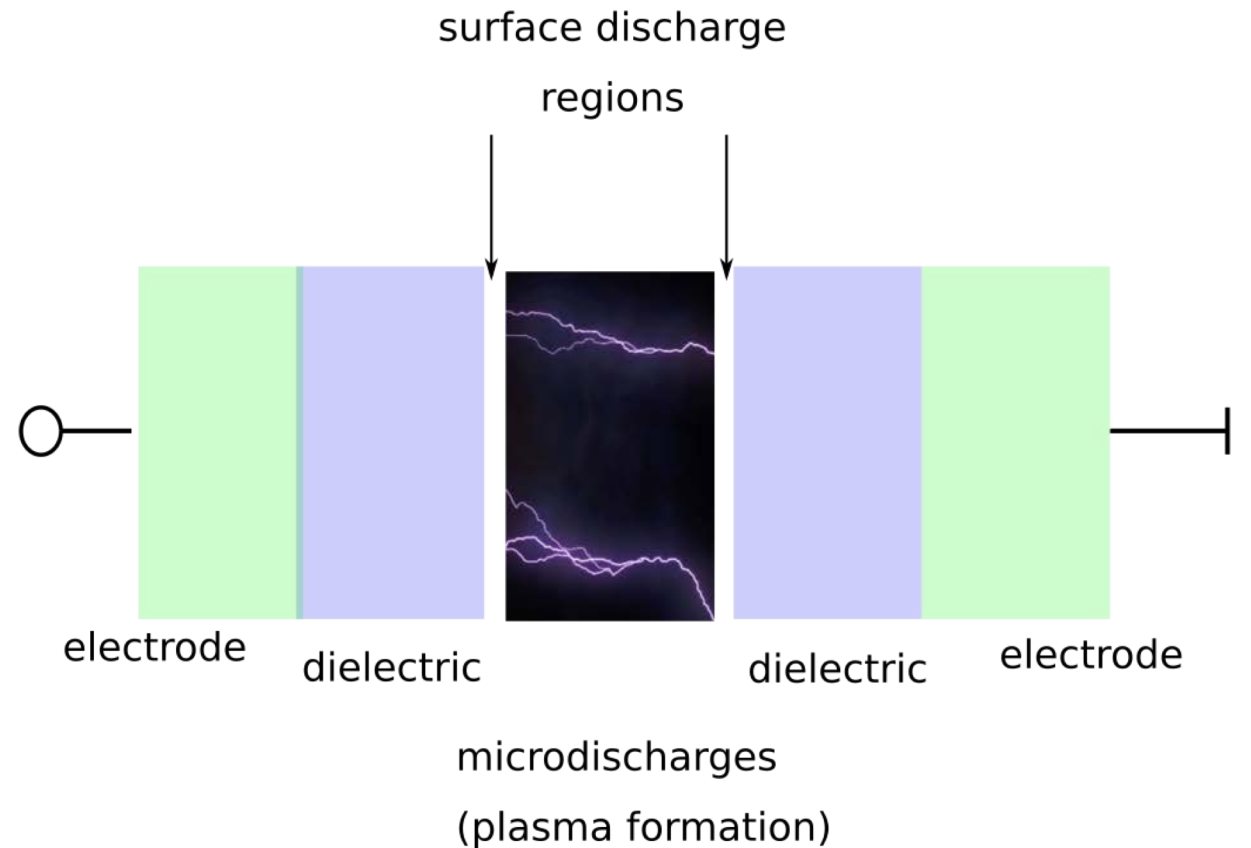


DOE/NNSA/ASC/PSAAPI:
The Center for Exascale Simulation of
Plasma-coupled Combustion



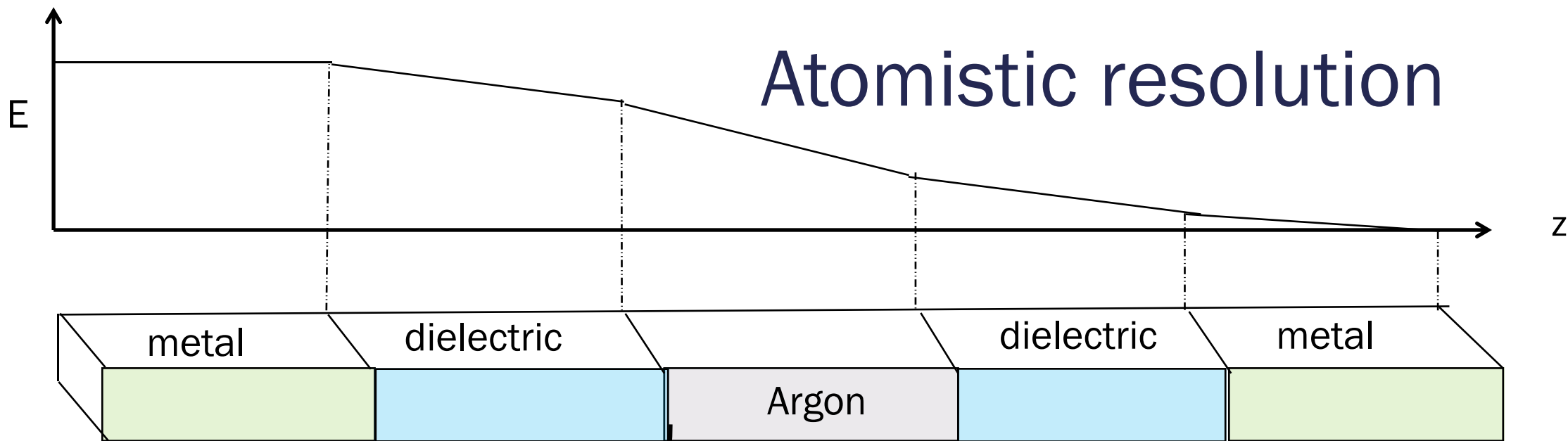
We use Blue Waters to ...

- Develop large scale electronic structure calculations
- Investigate nano and microscale dielectric barrier discharges
- Technological applications in microcombustion, chemical processing

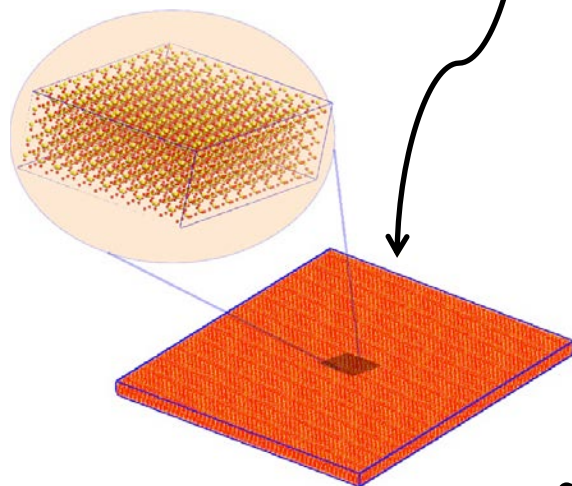


Dielectric barrier discharge, first reported by Siemens, 1857.

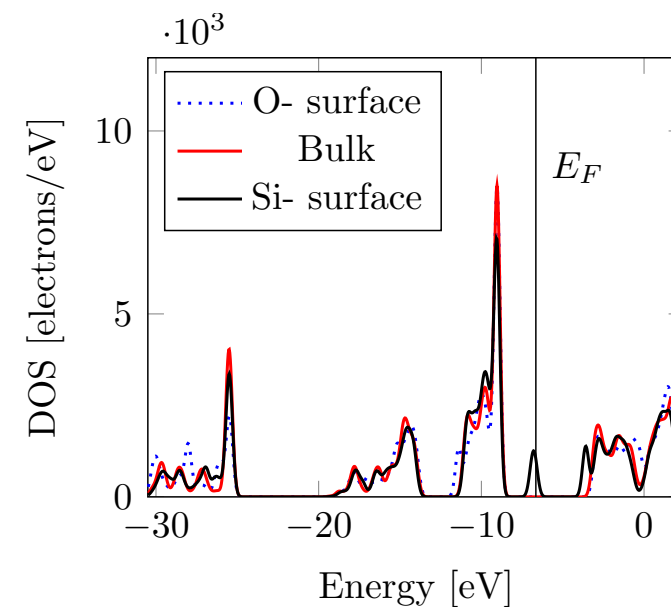
Atomistic resolution



$\sim 10^8$ atoms

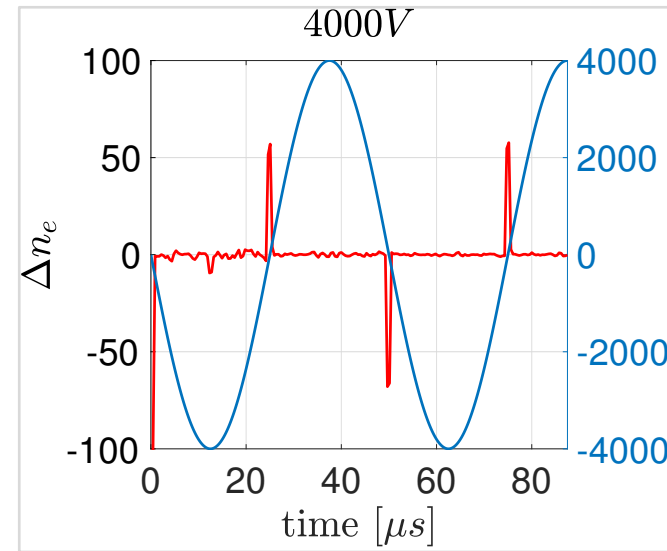


$\sim 10^6$ atoms



Of interest:

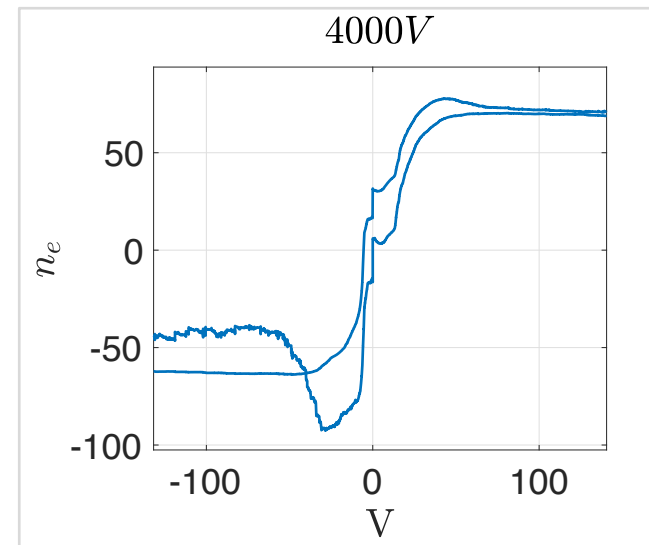
- A microscopic understanding of DBD devices
- So far, qualitative agreement with experiments



Current as a function of time

Red: Rate of electron emission from the dielectric

Blue: AC voltage. 4000V, $f = 20\text{kHz}$

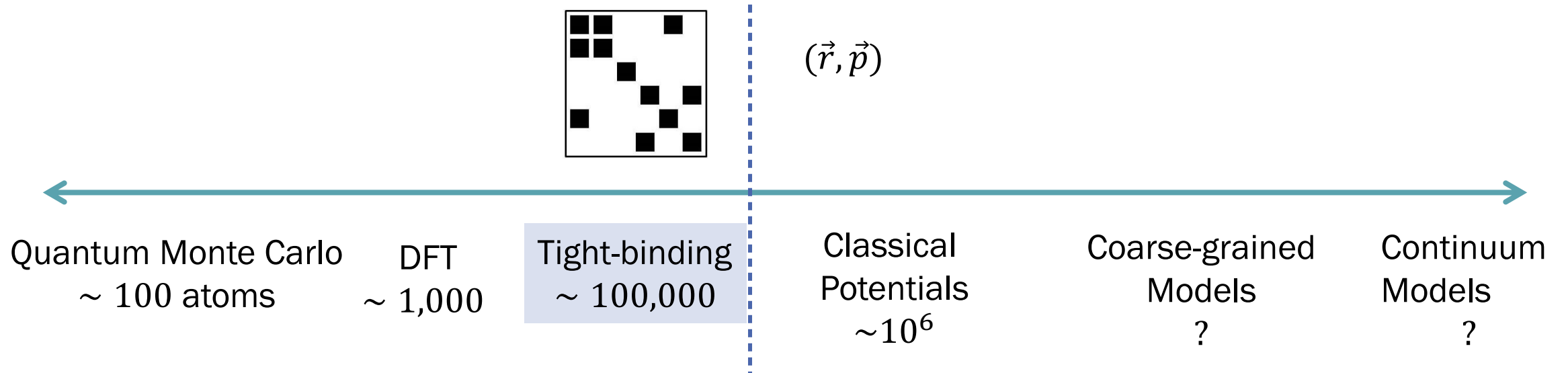


Lissajous plot under AC voltage

Surface charge on the dielectric under AC voltage.

[Ghale and Johnson, *Phys. Rev. B*, 2019]

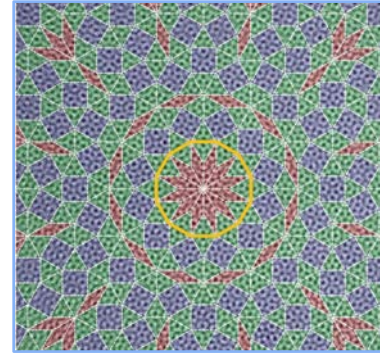
Overview of methods



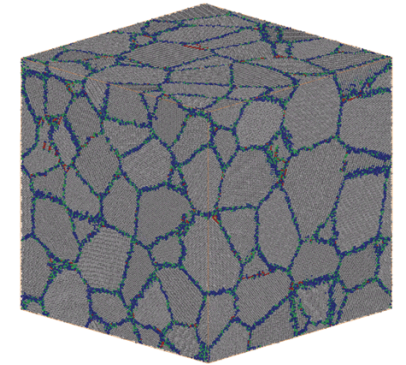
Tight-binding is the least expensive method that can still give us quantum-mechanical information about electrons at the atomistic level (bandgaps, transport, charge-density)

Possible Computations

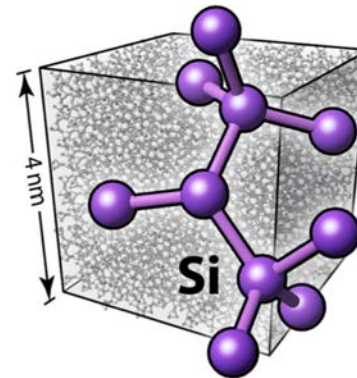
- Systems for which classical molecular dynamics have been done
- Disordered systems
- Systems without translational symmetry
- Glasses and liquids



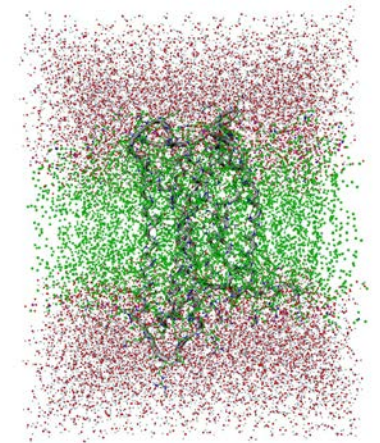
Carbon quasi-crystal
Ahn et. al. Science, 2018



Polycrystalline Ni
Swygenhoven,
Science, 2002



Quenched amorphous-Si
Deringer, et al.,
J. Phys. Chem. Lett., 2018



Protein, lipid bi-layer, water
Zuse Institute Berlin

Background

$$\left(\sum_i \frac{\nabla_i^2}{2m} + V_{ext} + \frac{1}{2} \sum_{i \neq j} \frac{1}{|x_i - x_j|} \right) \Psi(x_1, \dots, x_N) = E \Psi(x_1, \dots, x_N)$$

$$\sum_i \underbrace{\left(\frac{\nabla_i^2}{2m} + V_{eff,i} \right)}_{\hat{H}_i} \Psi(x_1, \dots, x_N) = E \Psi(x_1, \dots, x_N)$$

$$(\hat{H}_1 + \hat{H}_2 + \dots + \hat{H}_N) \Psi = (E_1 + E_2 + \dots + E_N) \Psi$$

Separation of variables : $\frac{\hat{H}_1}{\psi_1} \psi_1 + \frac{\hat{H}_2}{\psi_2} \psi_2 + \dots = E_1 + E_2 + \dots + E_N$

Indistinguishability/anti-symmetry

$$\hat{H} \psi_i(x_i) = \epsilon_i \psi_i(x_i)$$

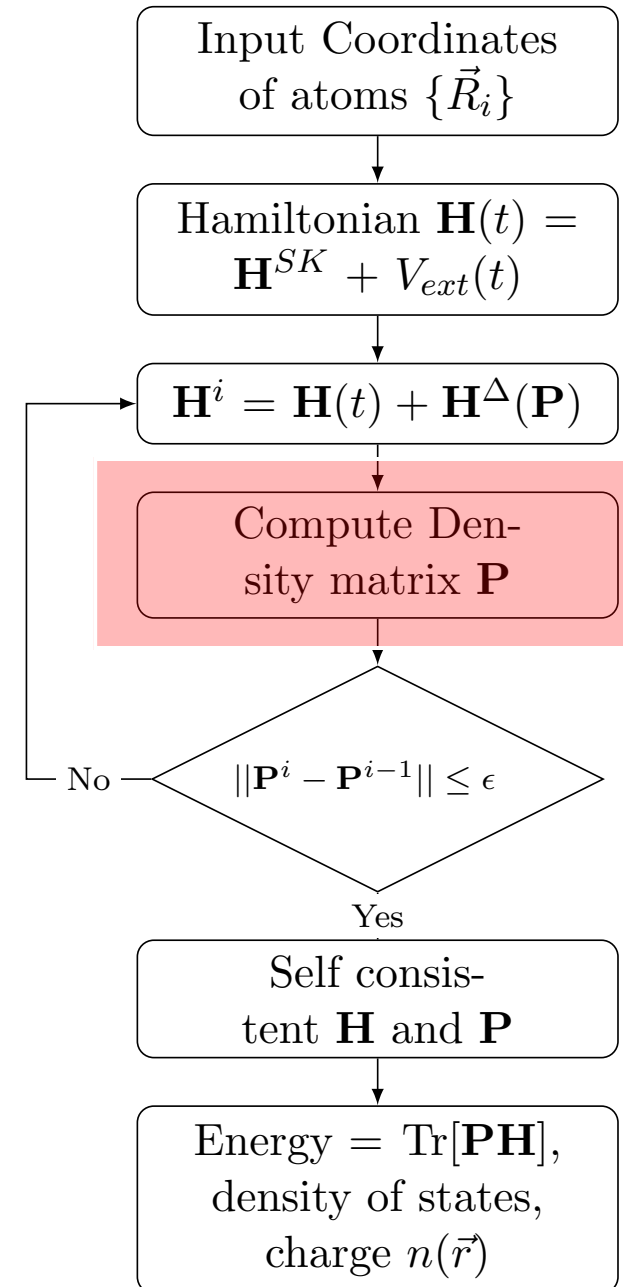
$$H \vec{v}_i = \epsilon_i \vec{v}_i$$

Computation

- Given matrix H , compute P where

$$H\vec{v}_i = \epsilon_i\vec{v}_i$$
$$P = \sum_i \vec{v}_i \vec{v}_i^T$$
$$P^2 = P$$

- Each rank of P represents an electron
- Large eigenspace problem

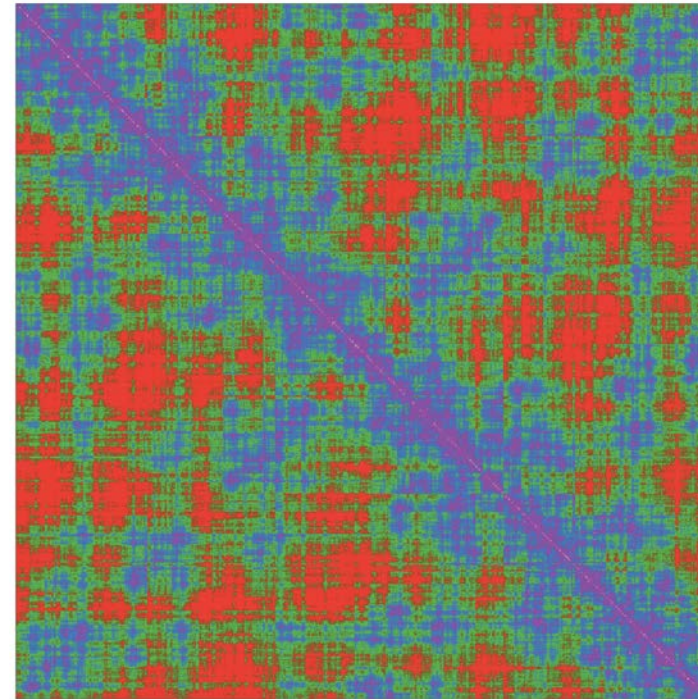


Algorithms

- $O(N)$ in terms of FLOPS
- Rely on localization of solution matrix
- Expect P to be sparse
- Sparse matrix-matrix multiplication (SpMM)

Red 10^{-8}
Green 10^{-6}
Blue 10^{-2}
Violet 1

Sparsity

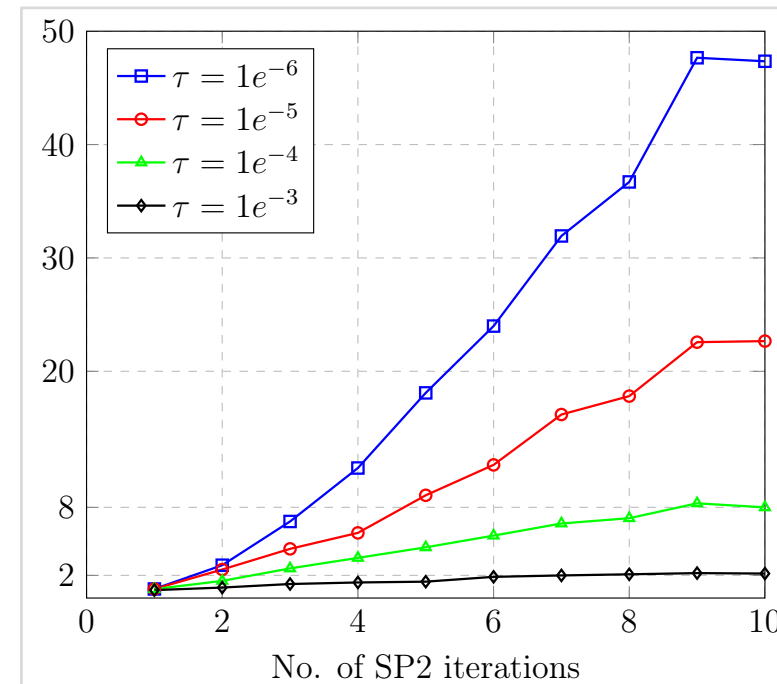


Density matrix (matrix size = 7500)

(Water) Bock and Challacombe *SIAM J. Sci. Comput.*, 2013

Challenge:

- Memory and communication
- Even for a moderate threshold, the % of non-zeros grows fast.
- Sparse matrix-matrix multiplications (SpMM)



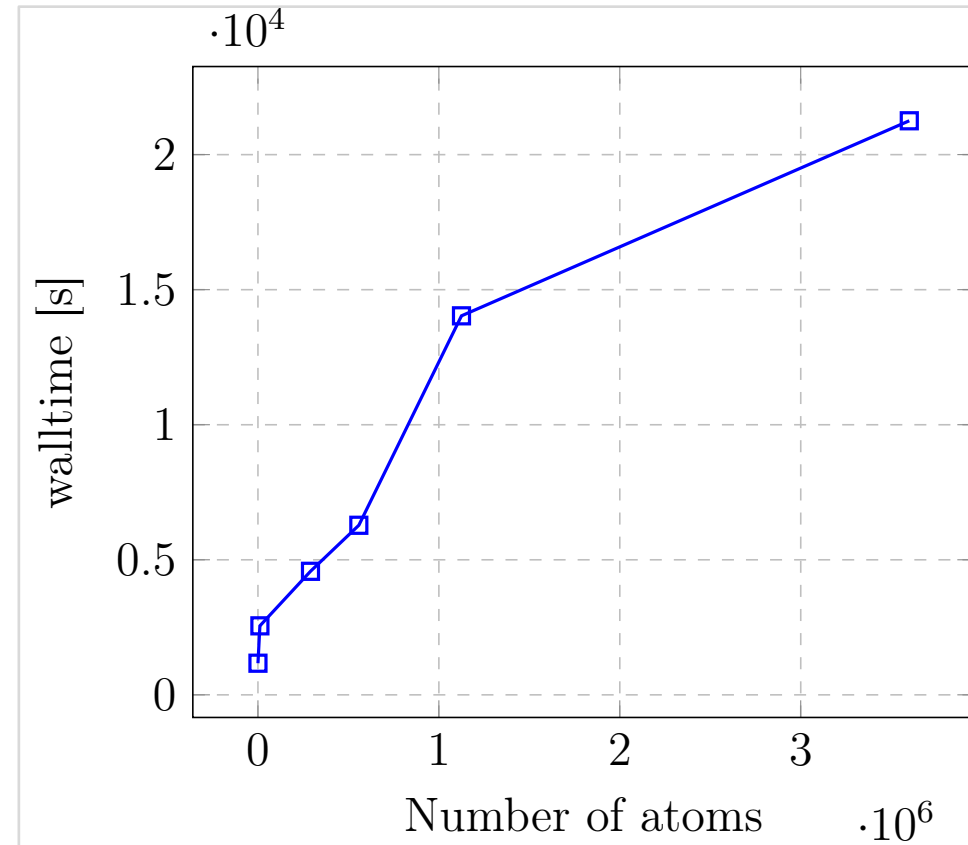
With the threshold parameter $\tau = 10^{-4}$, the memory required increases by a factor of 4.

Increase in % of non-zeros in density matrix

(Silica) Ghale and Johnson, *Comput. Phys. Comm.*, 2018

Our solution

- Memory-aware
- Based on Sparse-matrix-vector multiplications (SpMV)
- Construct implicit solution (P)
- Sampled via random vectors



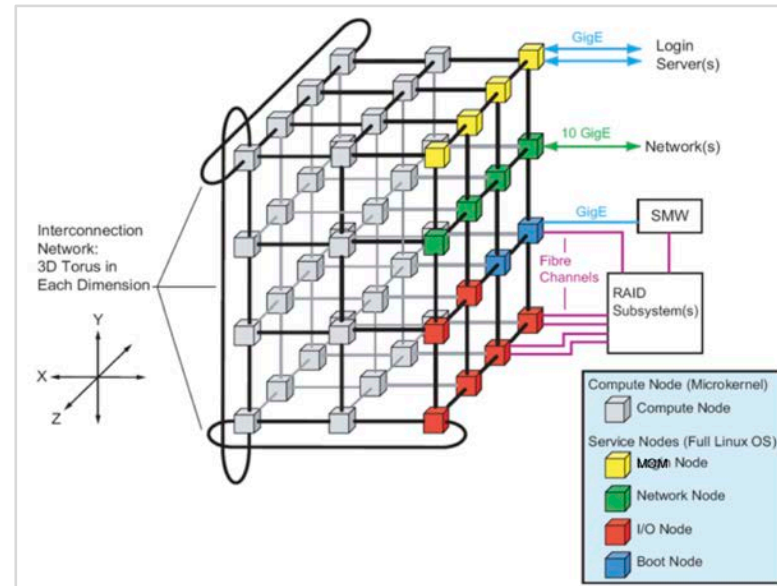
Simulation of 3.6 million atoms on a single large memory node. ~6 hours

Ghale and Johnson, Comput. Phys. Comm., 2018

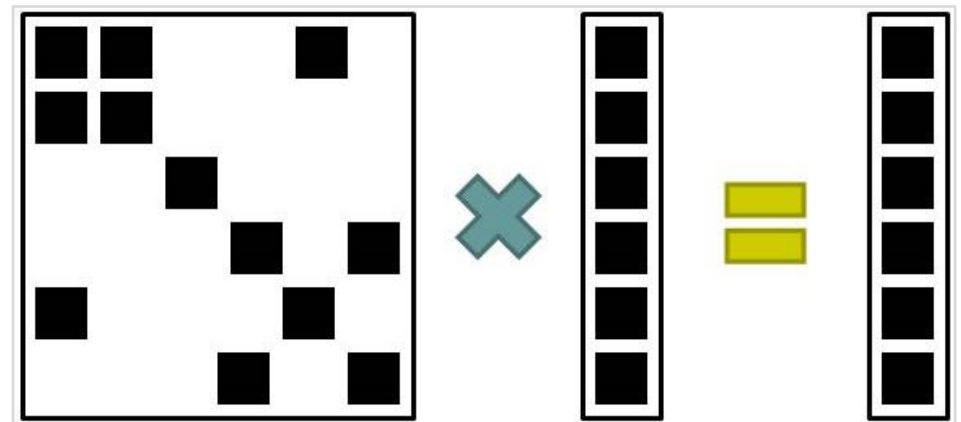
Role of Blue Waters:

- Scale of hardware
- Optimized libraries

Availability of fast, distributed, optimized SpMV kernels through PETSC



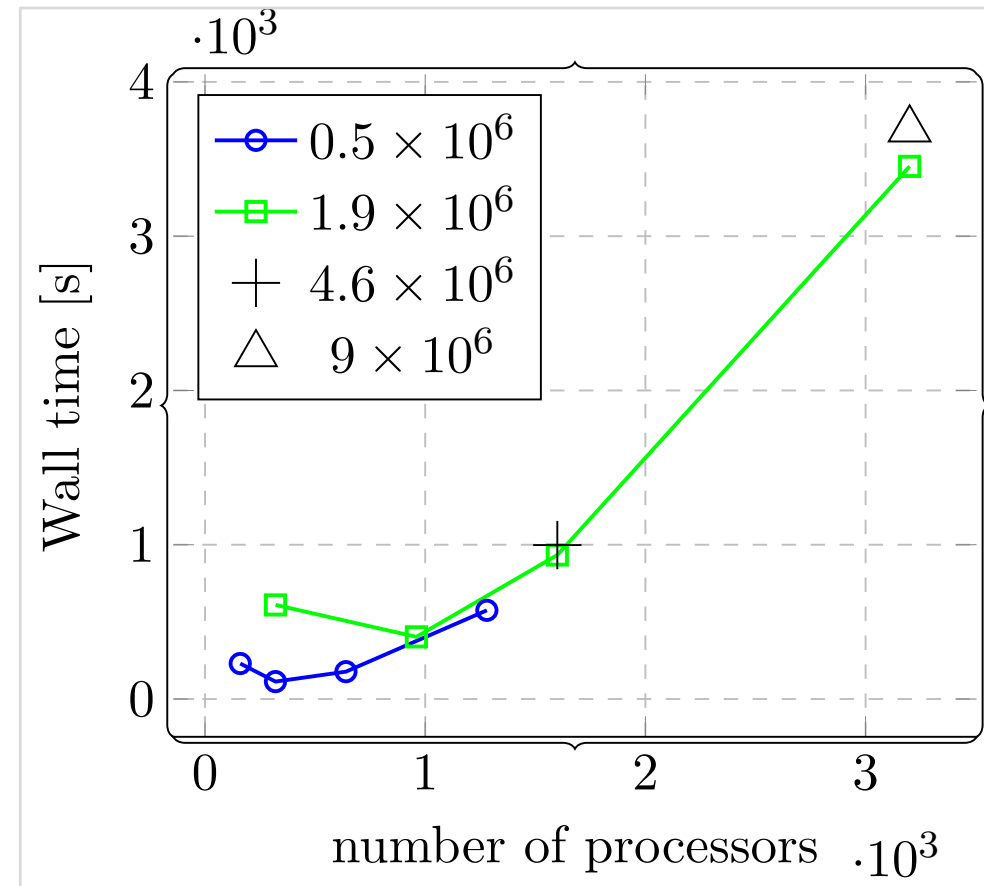
x 10,000 nodes (some testing)



Tested 10^7 atoms

Impact of Blue Waters

- Scaling up to 10^8 atoms
- Time-dependent simulations
- Essential electron emission data
- Current allocation: bawi



Scaling data (Exploratory allocation, baoq)

Future work/other impacts:

- Technical impact within area
 - *Ability to solve large systems self-consistently*
 - *Rates of electron transfer for plasma devices*
- Outside materials science
 - *fast, implicit, accurate, projection matrices*
- Future
 - *Time-dependent Hamiltonian (AC voltage)*

Acknowledgements

- This material is based [in part] upon work supported by the Department of Energy, National Nuclear Security Administration, under Award Number DE-NA0002374.
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- Numerous discussions within XPACC (Center for Exascale Simulation of Plasma Coupled Combustion)



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